Classical Hall Effect (Edwin Hall-1879)

Standard Geometry for the Hall-effect:

Transverse electric field (Hall-Field) just cancelled the Lorentz force due to magnetic field



Classical Hall Effect

Two resistivity components:

 ρ_{xx} : Longitudinal resistivity (Magneto-resistance) ρ_{xy} : Transverse resistivity (Hall resistance)

Resistivity is the property of material and is independent of shape and size. Resistance is related to resistivity as For 3D: $R = \rho (L/A) = \rho L^{2-D}$

General: Variation of longitudinal and transverse resistivity's as a function of magnetic field.

 $\rho_{xx} = 1/(ne\mu) = constant$

 ρ_{xy} = B/(ne) = proportional to B



Quantum Hall Effect (QHE) (K. von Klitzing-1980)

Low dimensions: 2D (Thin film-restricting third z-dimension) High Magnetic field (Tesla)

Low temperature

The striking feature of the quantum Hall effect is the persistence of the quantization

 ρ_{xy} :are in units of h/e² and are universal i.e. independent of materials. ρ_{xx} : Zero most of the time but shows peak when shows transition from one plateau to another. It is going under a transition from metal to insulator.

 ρ_{xy} = (h/e²)(1/ γ) where γ is an integer



Landau magnetic sub-bands



Effect of magnetic field on the Fermi-energy levels of 2 dimension electron gas. (a) and (d) the states in the absence of magnetic field. Each circle corresponds a energy levels states with qunatum number n having energy (n+1/2) $\hbar\omega$. The area between the two successive circles = $\pi\Delta(k^2) = (2\pi m/\hbar^2)\Delta E = 2\pi eB/\hbar c$.

The number of orbital in one magnetic sub-band = $(2\pi eB/\hbar c)(L/2\pi)^2$. (spin ignored)

Quantum Hall Effect (QHE) (K. von Klitzing-1980)

From the expression of Landau magnetic sub-bands: Number of orbital's (degeneracy) in one Landau level is given by $D = (eB/hc).L^2$ (Refer to your notes) where L is dimension of the sample. So, the number of states per unit area in the Landau levels is given by $N/L^2 = eB/hc = N_0$ (say the degeneracy of Landau level per unit area)

Consider the situation when j Landau levels are completely filled then the number of electrons per unit area can be written as jN_0 .

Hall resistance is given by $R_H = B/Nec$ (from slide 1, CGS) = B/[(eB/hc)jec] = Bhc/e²Bjc= (h/e²)(1/j) Where j is integer. This is quantum hall resistance.

Fermi-Surface construction

Using the concept of quantization of electron orbit in magnetic field

 $S(1/B_{n+1} - 1/B_n) = 2\pi e/\hbar c$

Equal increments in 1/B produce similar orbits. The periodicity in 1/B is a striking feature of magneto oscillatory effect in metals at low temperatures: resistivity, susceptibility, heat capacity.